

The Abdus Salam International Centre for Theoretical Physics



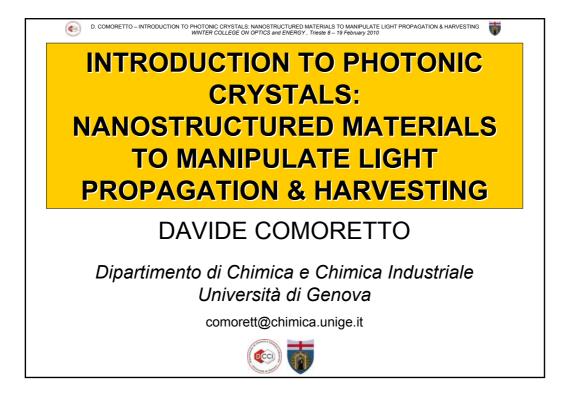
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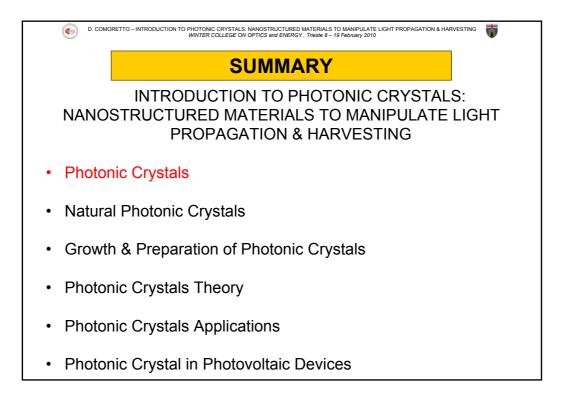
Winter College on Optics and Energy

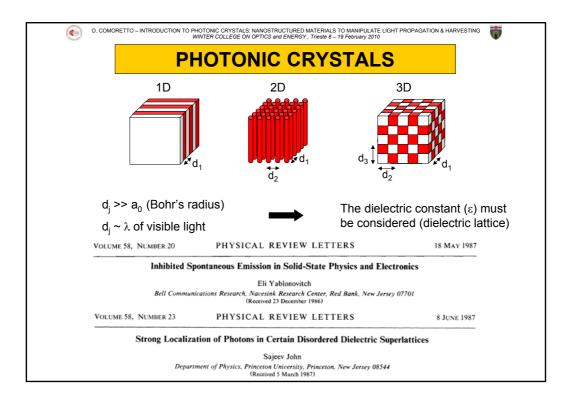
8 - 19 February 2010

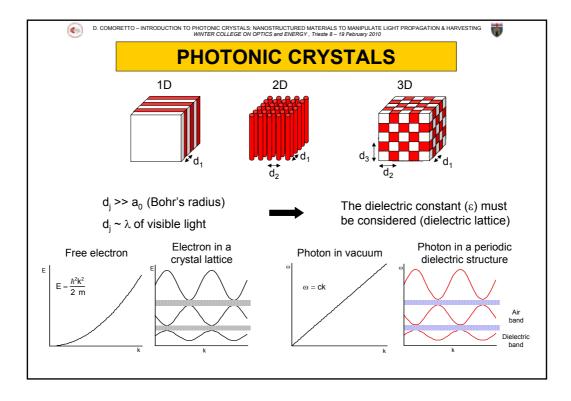
INTRODUCTION TO PHOTONIC CRYSTALS: NANOSTRUCTURED MATERIALS TO MANIPULATE LIGHT PROPAGATION & HARVESTING

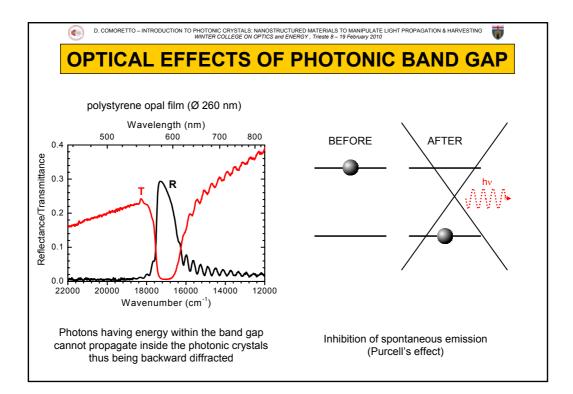
D. Comoretto Universita' di Genova Italy

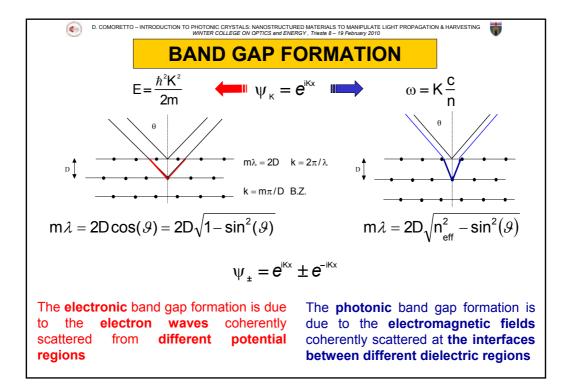


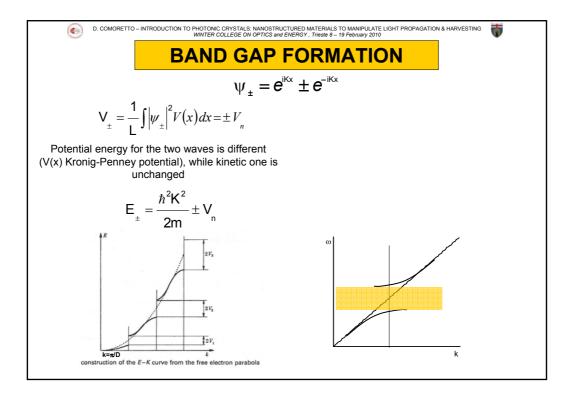


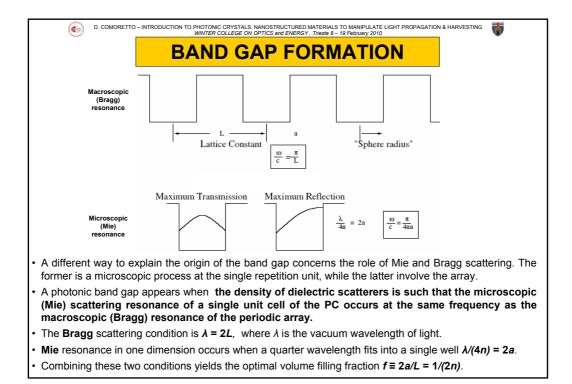


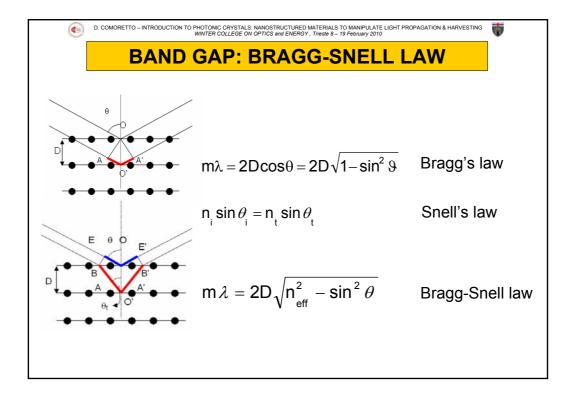


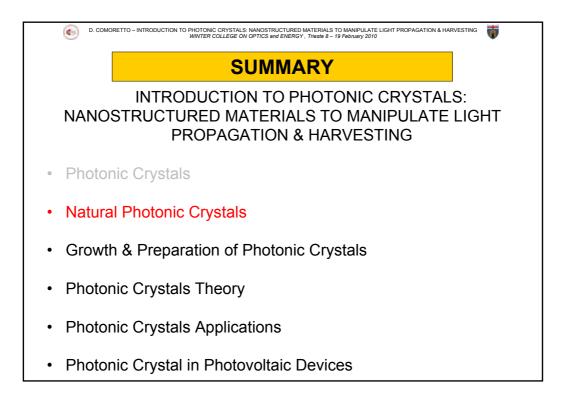


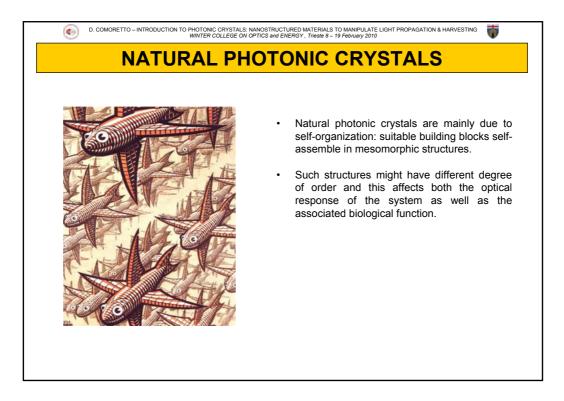


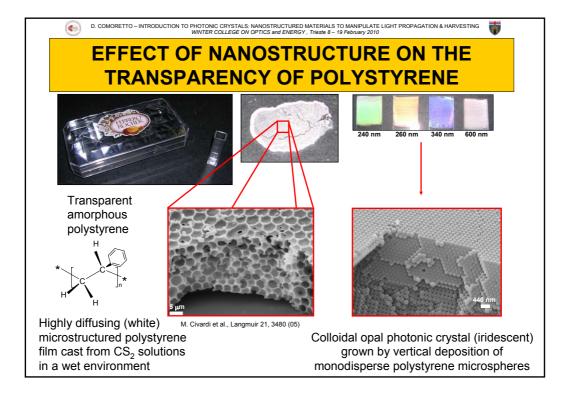


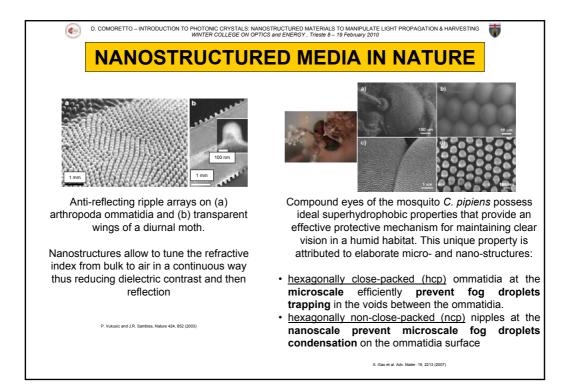


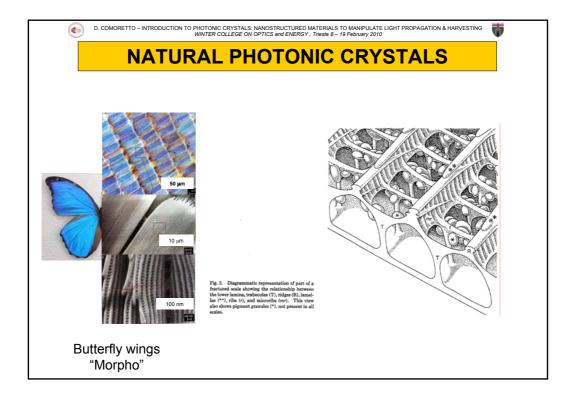


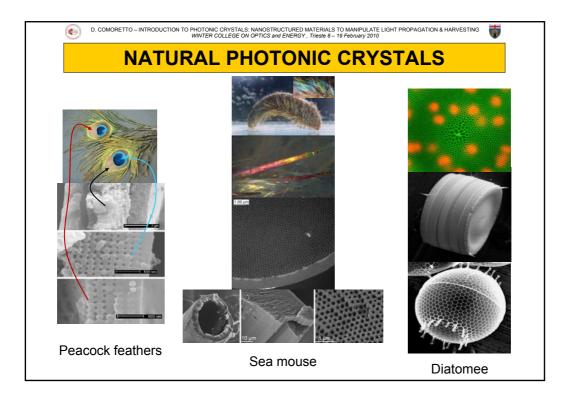


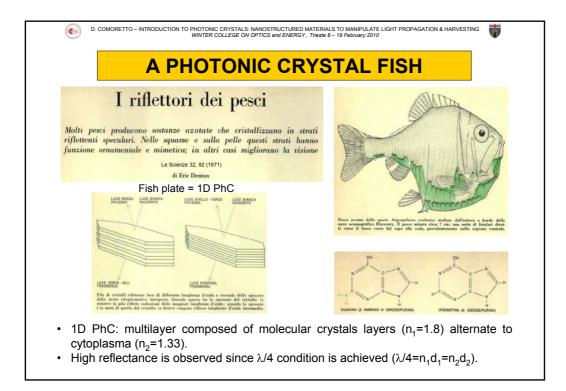


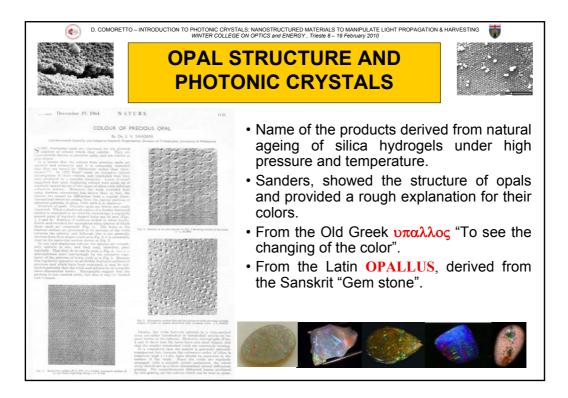


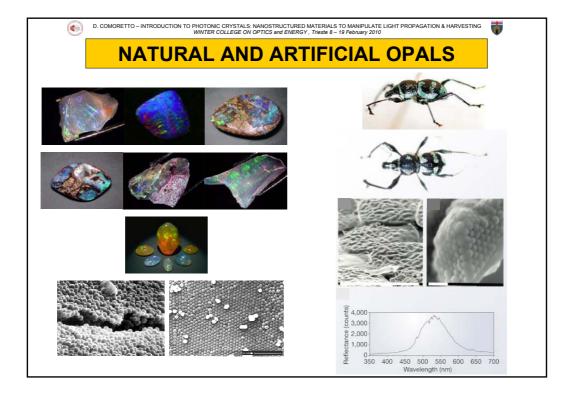


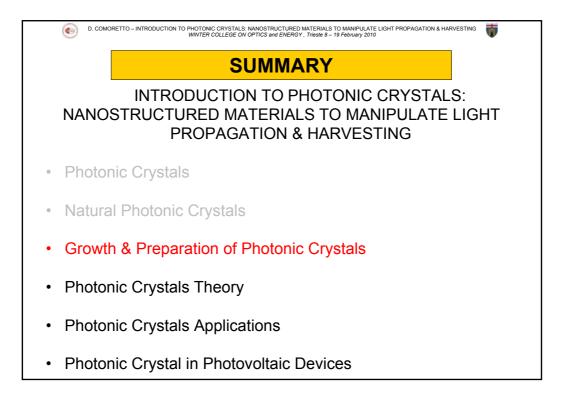


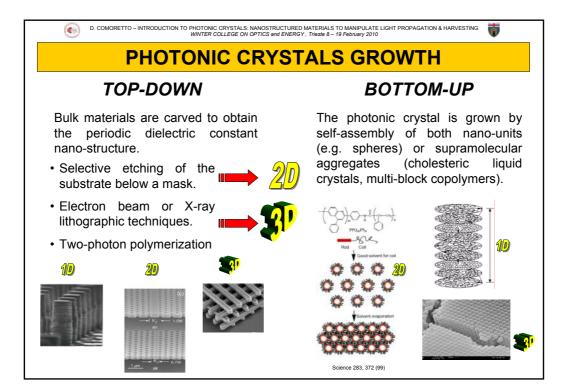


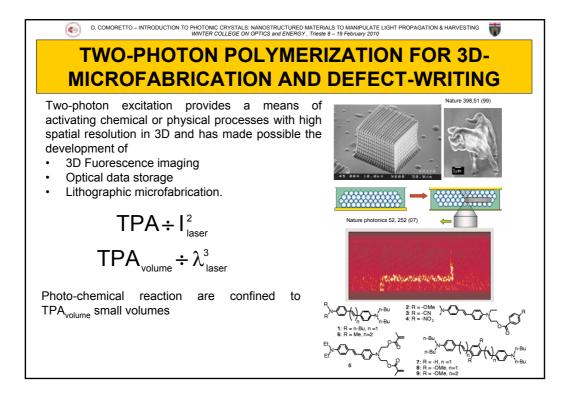


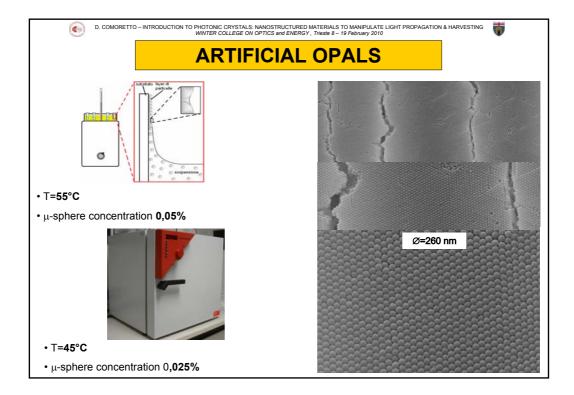


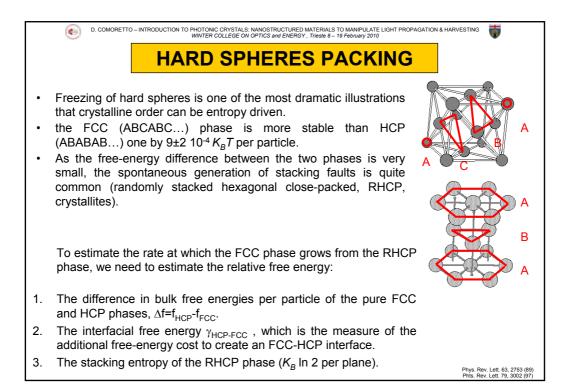


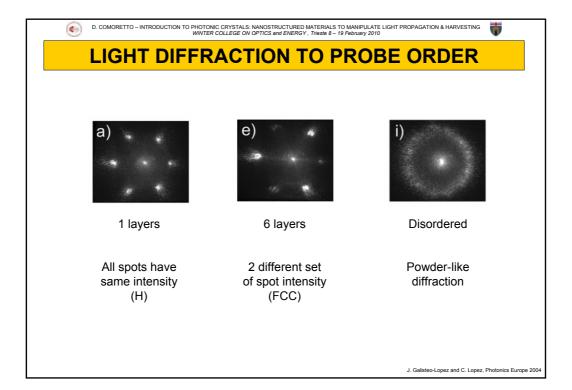


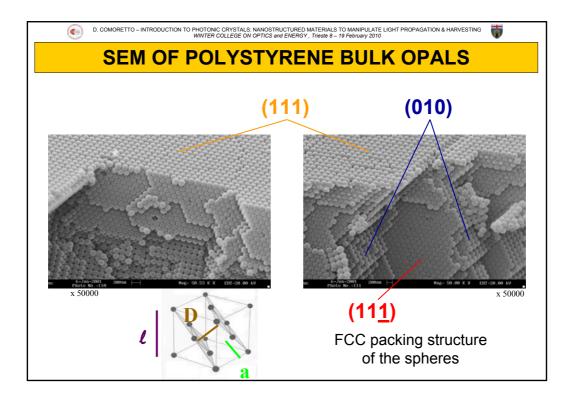


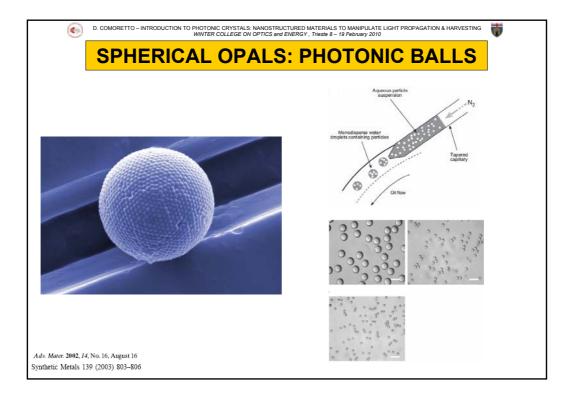


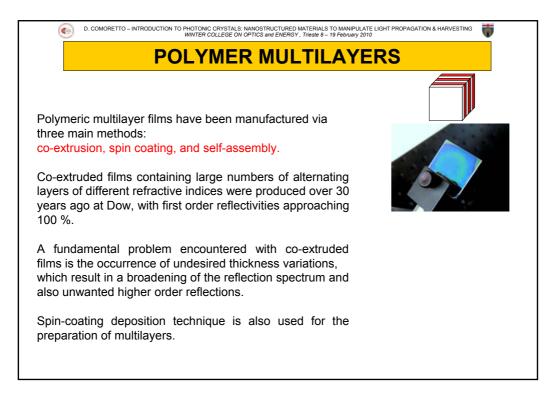


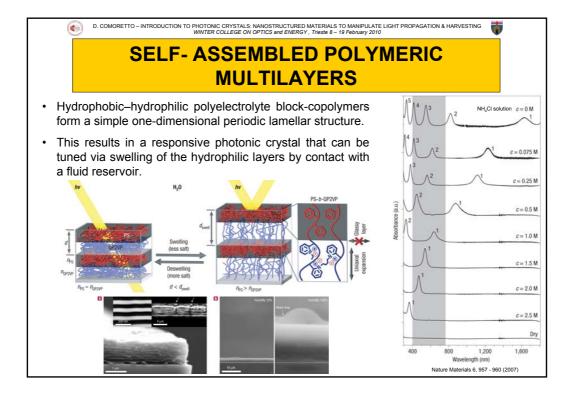


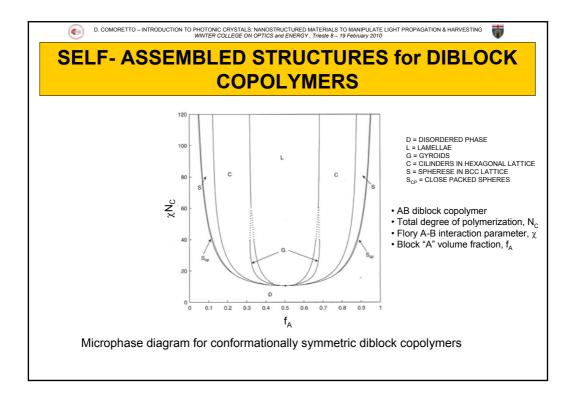


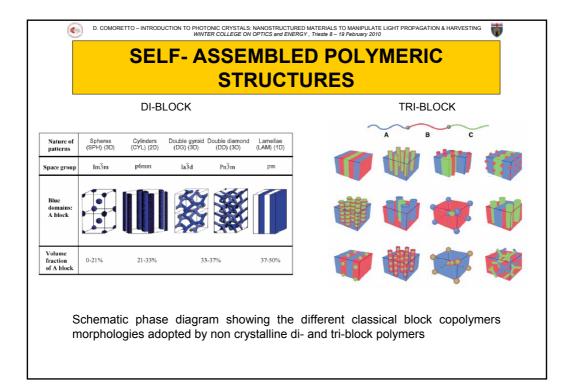


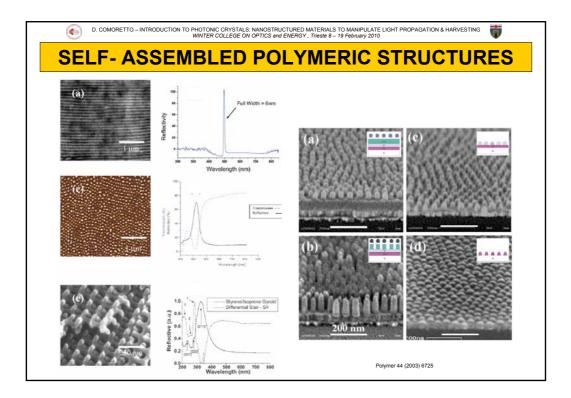


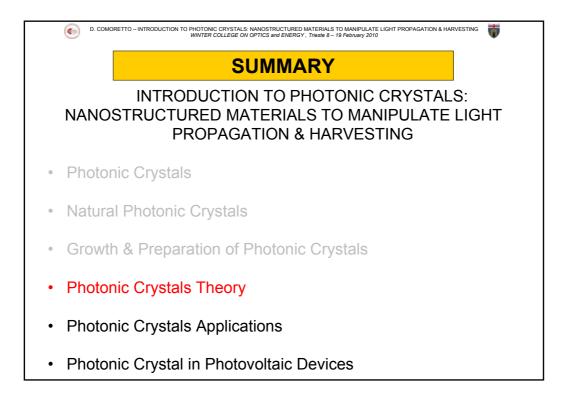


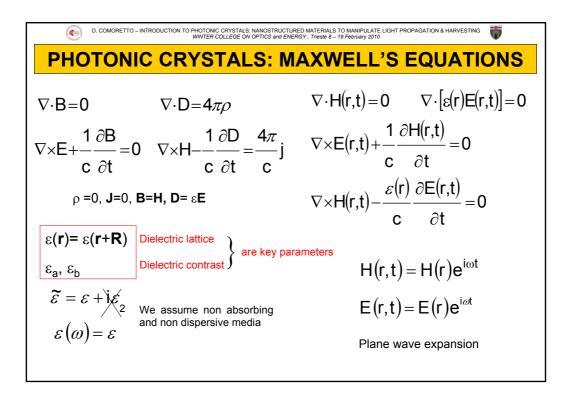


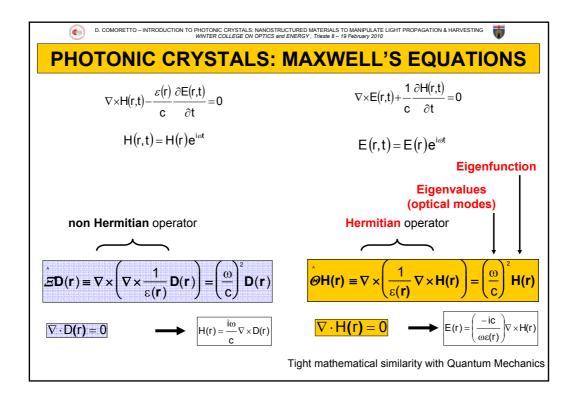


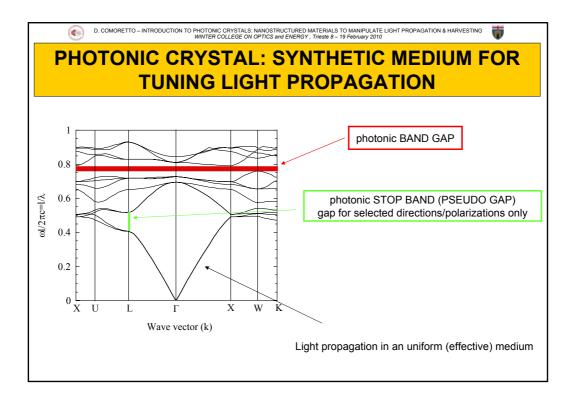


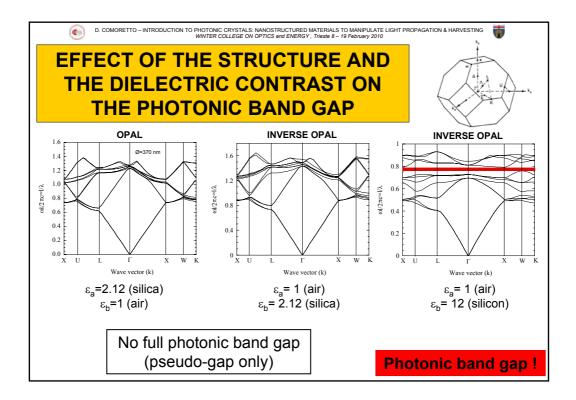


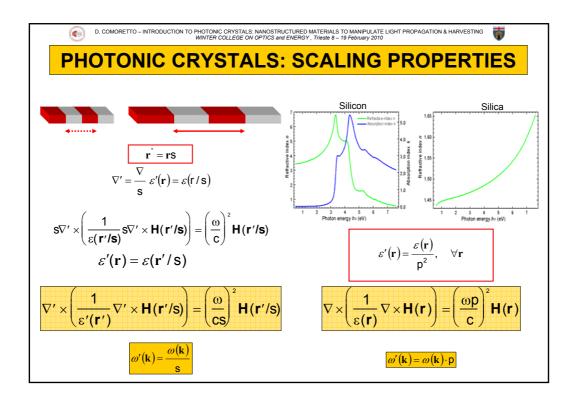


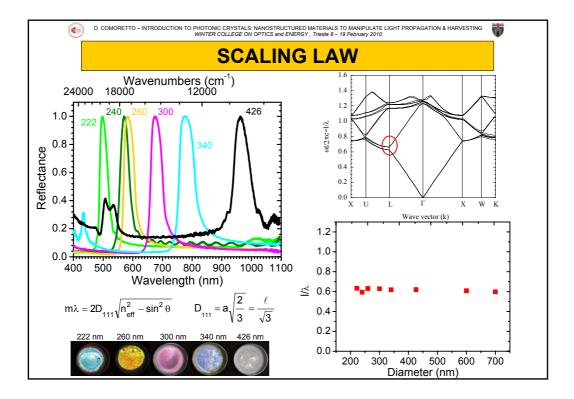


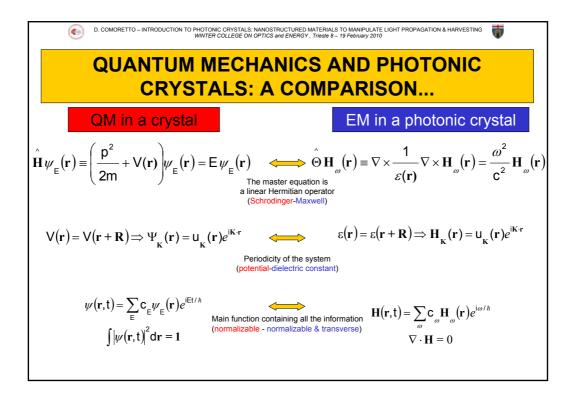


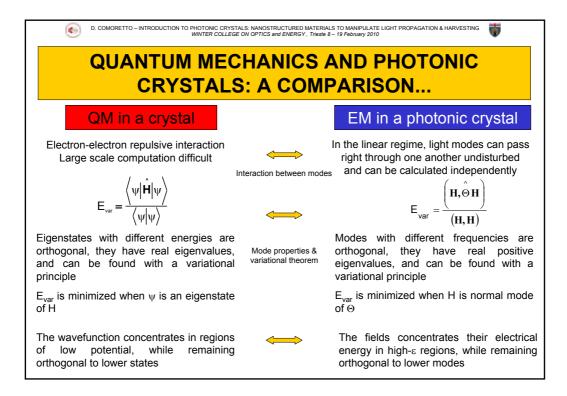




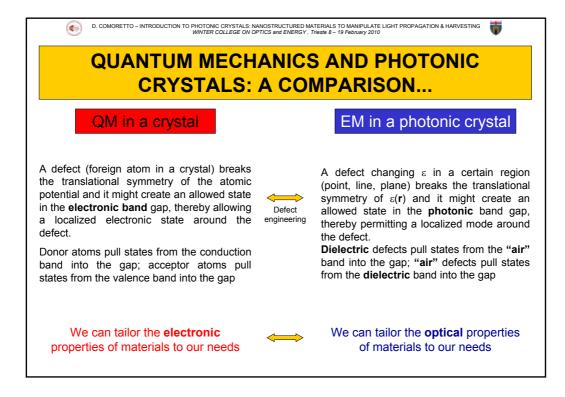


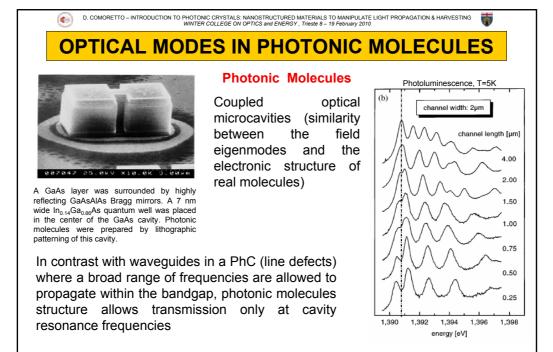






D. COMORETTO – INTRODUCTION TO PHOTONIC CRYSTALS: NANOSTRUCTURED MATERIALS TO MANIPULATE LIGHT PROPAGATION & HARVESTING WINTER COLLEGE ON OPTICS and ENERGY. Trieste 8 – 19 February 2010						
QUANTUM MECHANICS AND PHOTONIC CRYSTALS: A COMPARISON						
QM in a crystal	EM in a photonic crystal					
The eigenvalue E of the Hamiltonian	System energy	The electromagnetic energy $E = \frac{1}{8\pi} \int dr \left(\frac{1}{\varepsilon} D ^2 + H ^2 \right)$				
The natural scale of the system is provided by the Bohr radius	m is provided There is not a natural scale: the solution are scalable to any length					
Scale length of the system						
The band structure $E_n(\mathbf{k})$ tells us the energies of the allowed eigenstates.		The functions $\omega_n(\textbf{k})$ tells us the frequencies of the allowed harmonic modes.				
The electron wave scatters coherently from the different potential regions	Band structure	The electromagnetic fields scatter coherently at the interface between different dielectric				
Inside the electronic gap no propagating	and gap	regions				
electrons are allowed to exist		Inside the photonic band gap no modes are allowed to exist				
The band above the gap is the conduction band; the band below the gap is he valence band		The band above the gap is the air band ; the band below the gap is the dielectric band				

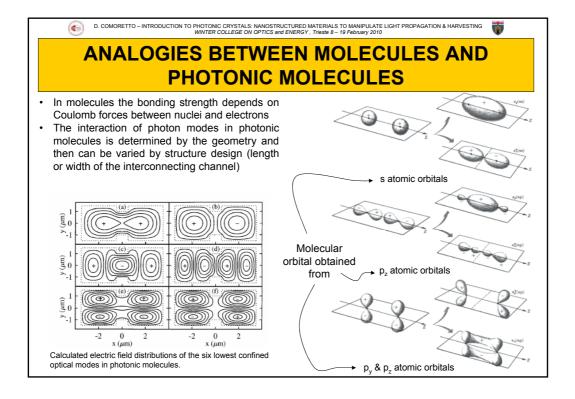




PHYSICAL REVIEW LETTERS

VOLUME 81, NUMBER 12

21 September 1998





ELECTROMAGNETIC VARIATIONAL THEOREM: AIR & DIELECTRIC BANDS

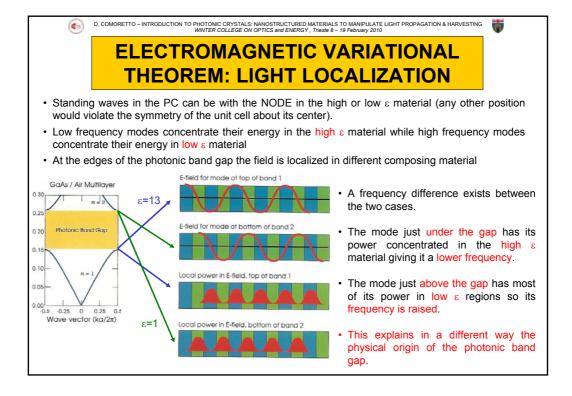
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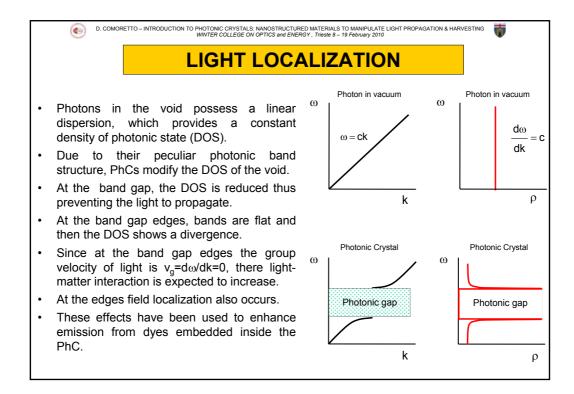
- Unlike electrons in a semiconductor which are constrained by Fermi statistics and therefore have to be excited from the valence band to the conduction band to become mobile, photons are bosons which propagate freely at frequencies both above and below the PBG.
- Thus the terms 'valence band' and 'conduction band' may not be appropriate in the context of a PhC.
- Instead, bands above and below a PBG can be distinguished by applying the electromagnetic variational theorem:

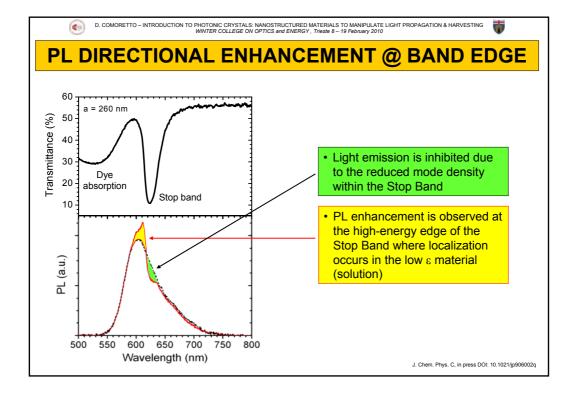
$$\mathsf{E}_{\mathsf{f}}(\mathsf{H}) = \frac{1}{2} \frac{\left(\mathsf{H}, \Theta \mathsf{H}\right)}{\left(\mathsf{H}, \mathsf{H}\right)} = \left(\frac{1}{2\left(\mathsf{H}, \mathsf{H}\right)}\right) \int d\mathbf{r} \frac{1}{\varepsilon} |\nabla \times \mathsf{H}|^2 = \left(\frac{1}{2\left(\mathsf{H}, \mathsf{H}\right)}\right) \int d\mathbf{r} \frac{1}{\varepsilon} \left|\frac{\omega}{\varepsilon}\mathsf{D}\right|^2 \qquad (\mathsf{F}, \mathsf{G}) \equiv \int d\mathbf{r} \,\mathsf{F}^*(\mathsf{r}) \cdot \mathsf{G}(\mathsf{r})$$

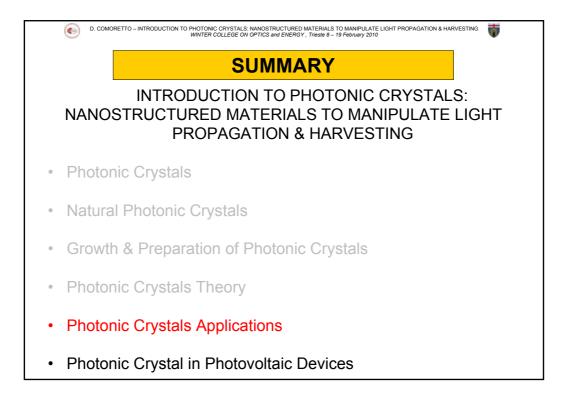
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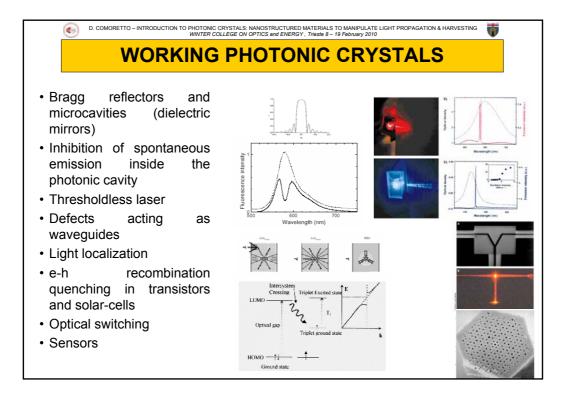
• According to this theorem, for modes in the lower photonic band, the power of modes lies primarily in the high-index regions, whereas for modes in the upper photonic band the power lies in the low-index regions. In PCs, the low-index regions are often air regions. For this reason it is more meaningful to refer to the band *above* a PBG as the '*air*' band, and the one below the gap as the '*dielectric*' band.

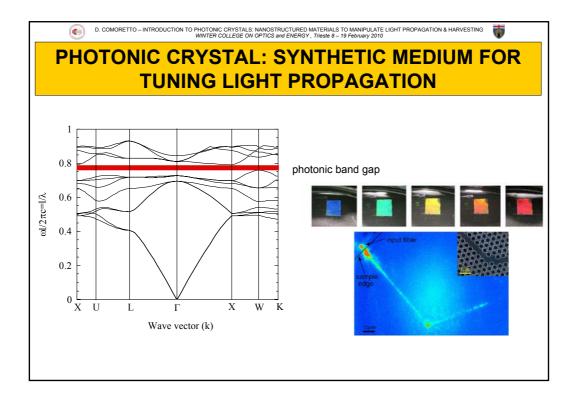


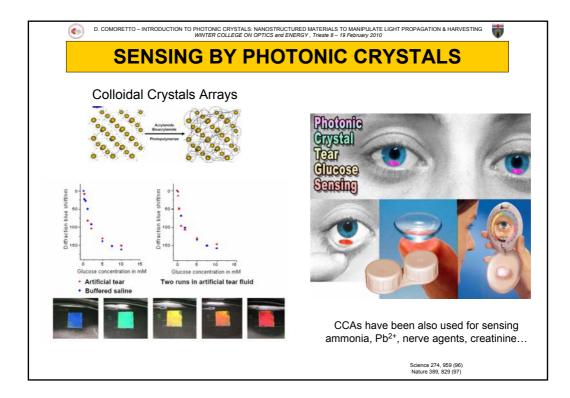


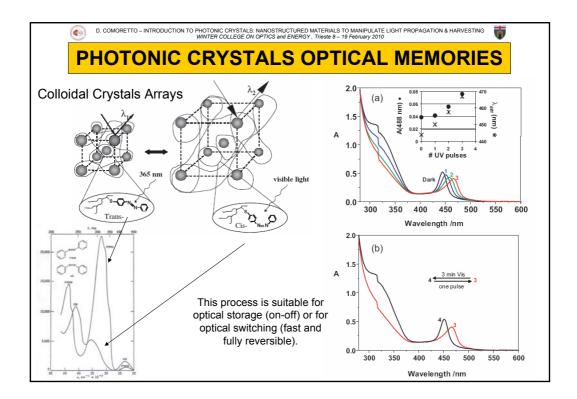


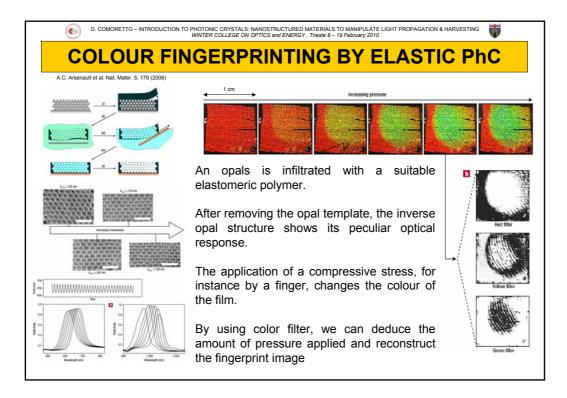


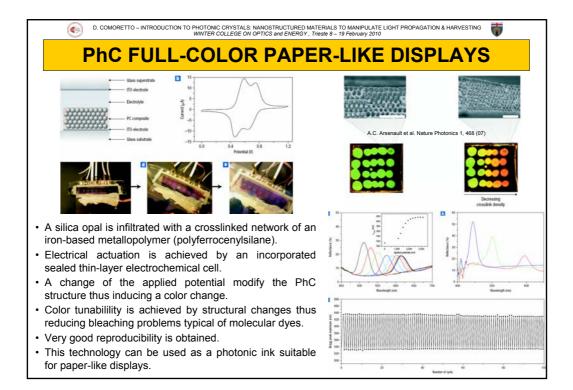


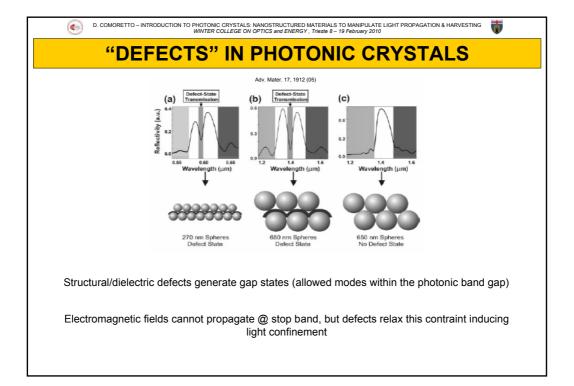


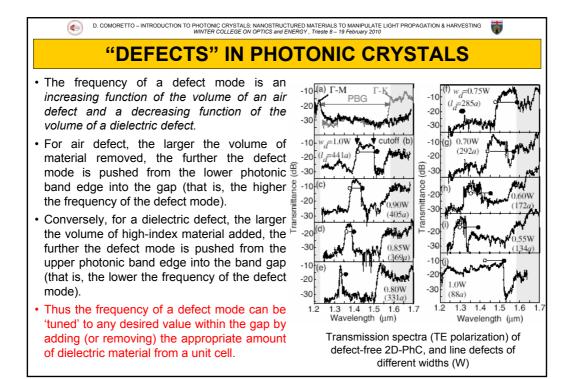


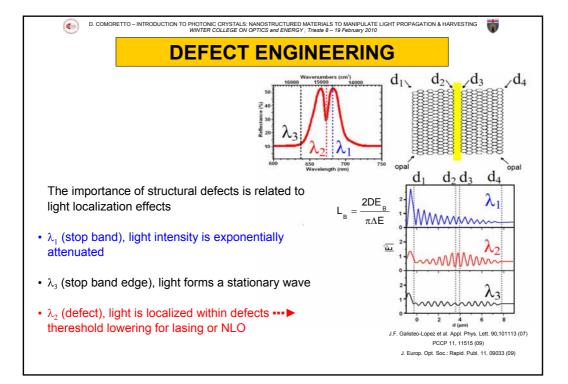


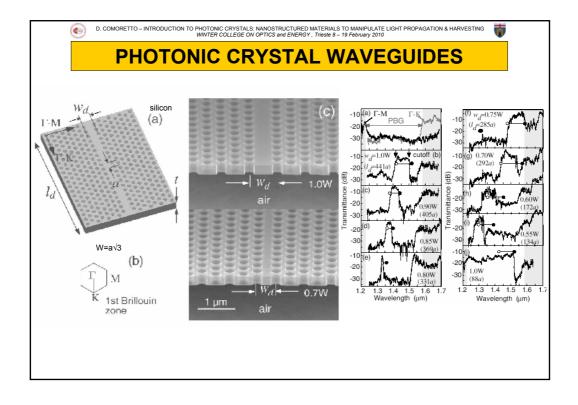


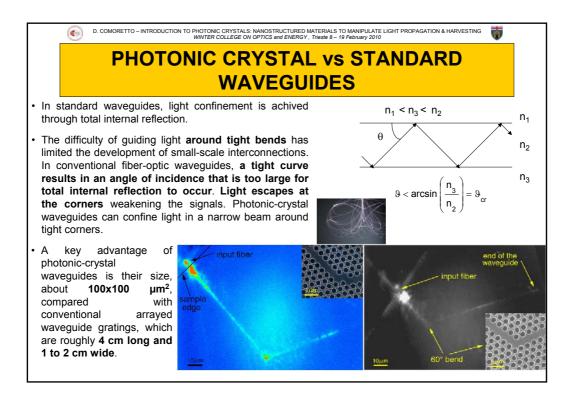


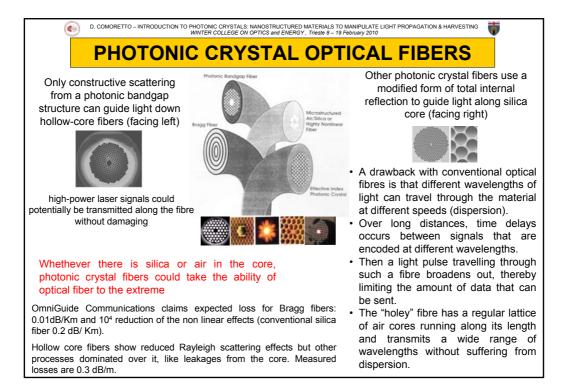


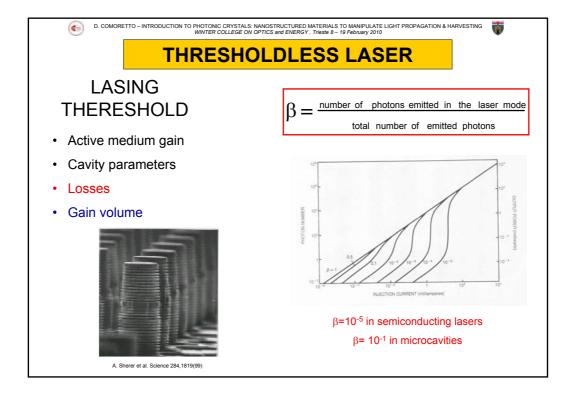


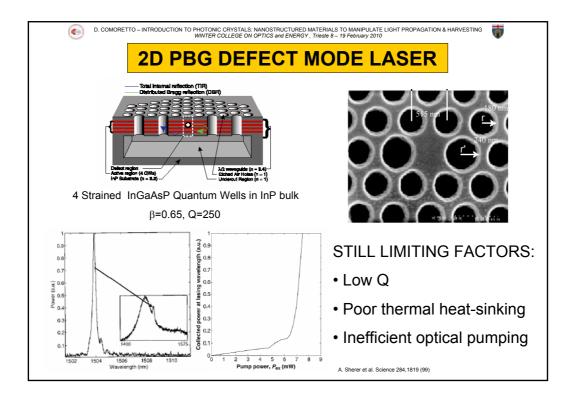


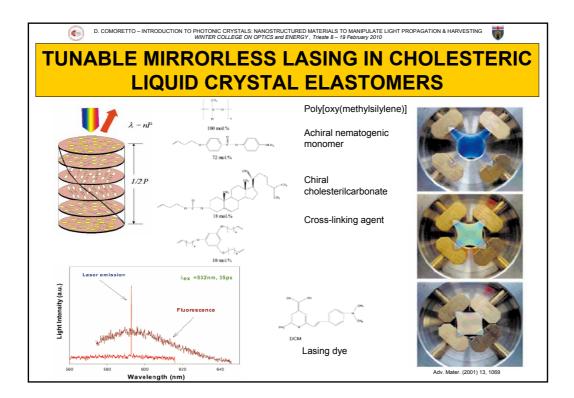


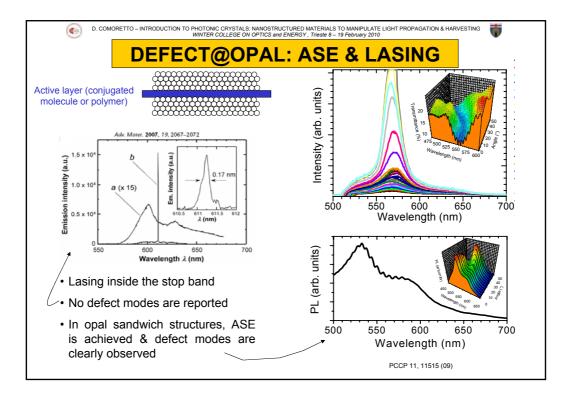


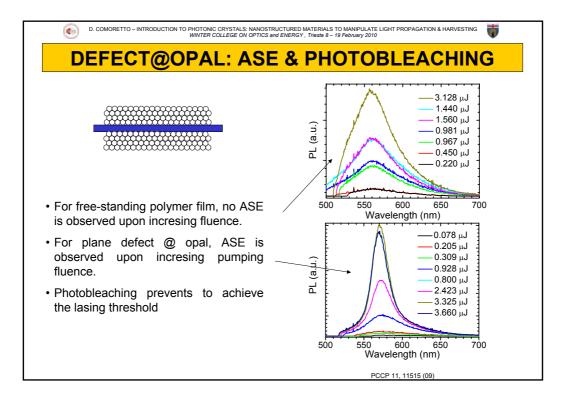


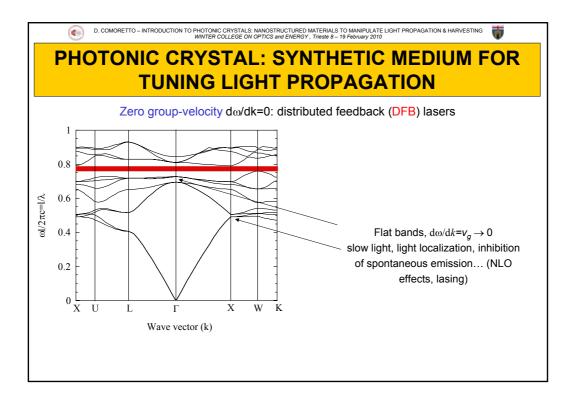


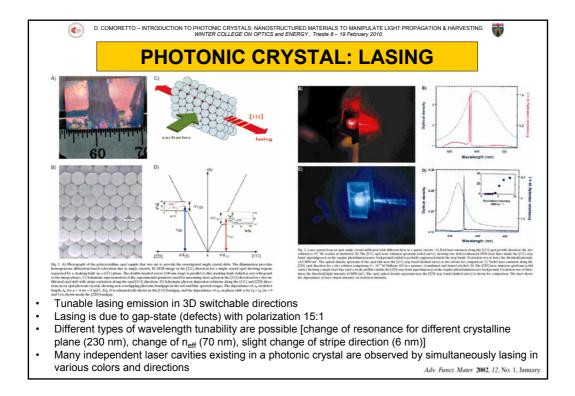


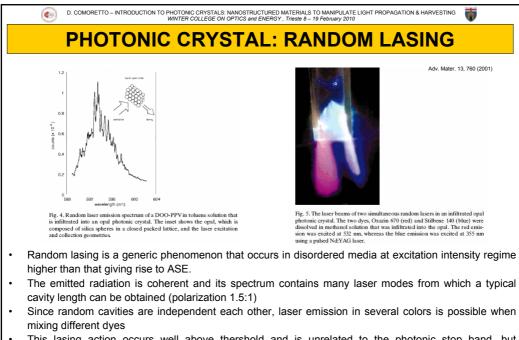




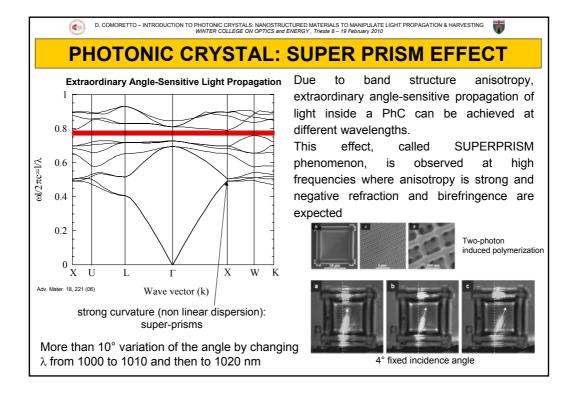


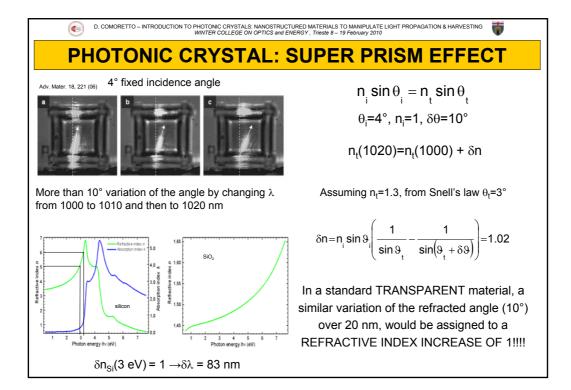


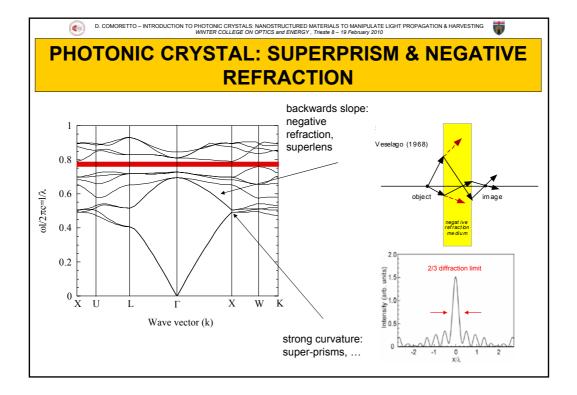


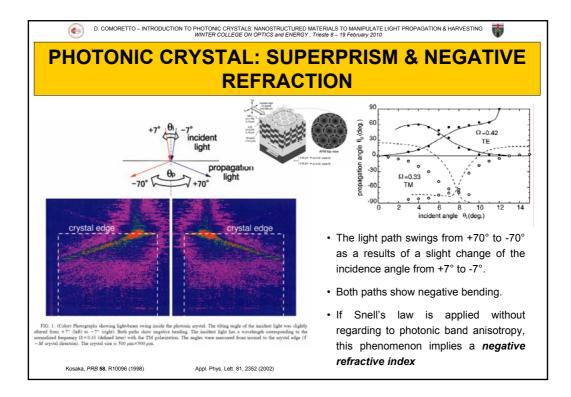


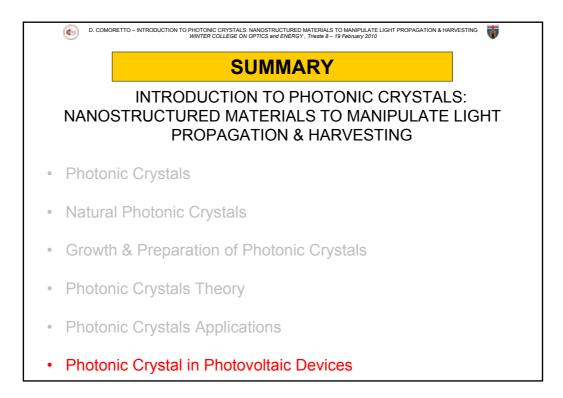
• This lasing action occurs well above thershold and is unrelated to the photonic stop band, but overlapped to the dye maximum emission spectrum

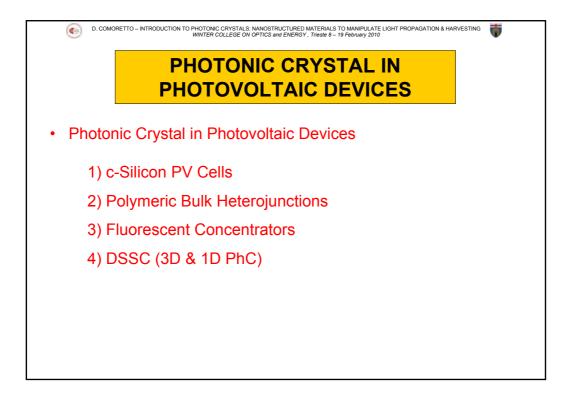


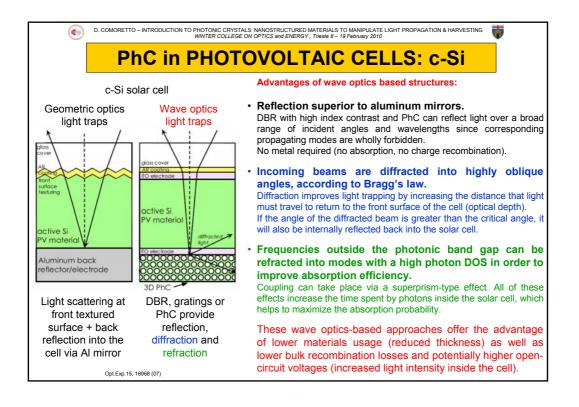


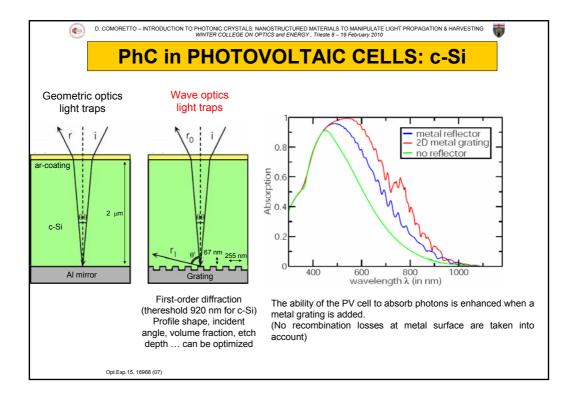




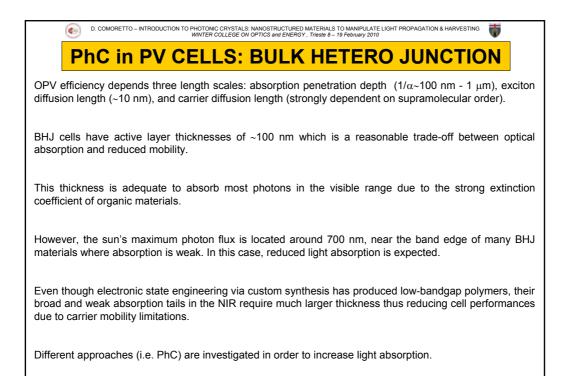


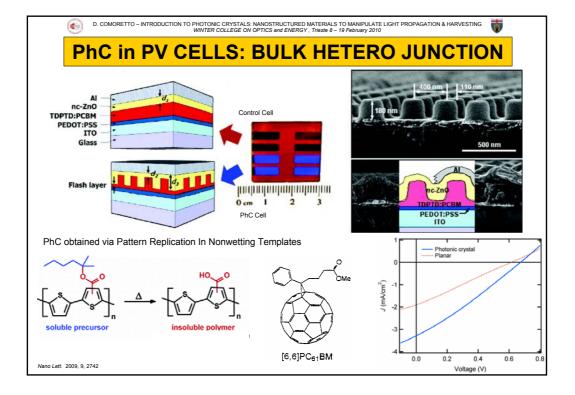


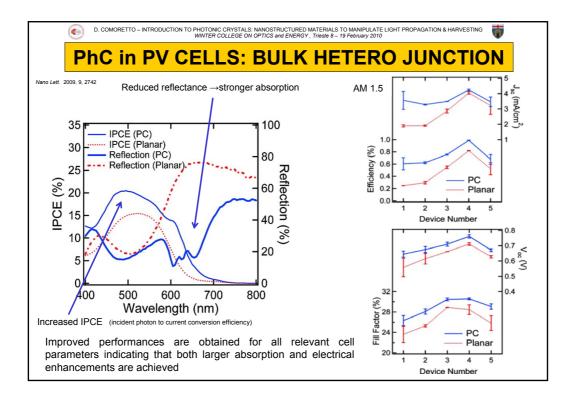


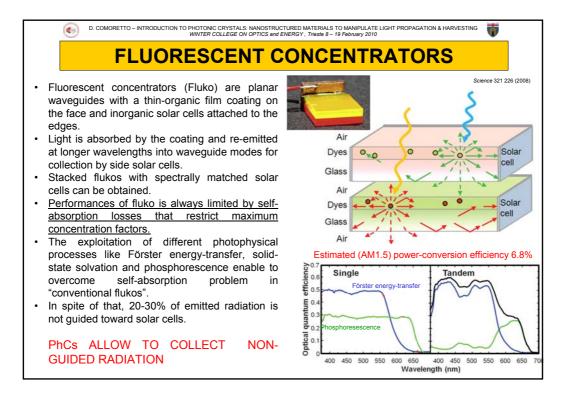


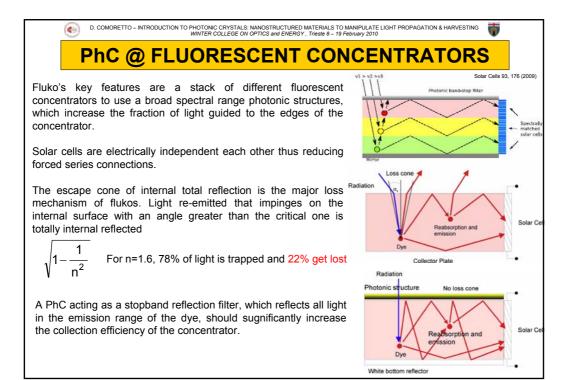
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PhC in PHOTOVOLTAIC CELLS: c-Si						
(a) r i/	(b) r ₀ i	(c) r ₀ i	Wave optics structure	PV Cell efficiency (%)		
c-Si		Al reflector ^{+,*}	12.72 (13.77)			
		Al grating ^{+,*}	(17.88 1D-19.29 2D)			
		DBR (8 periods)	<u>12.44</u>			
		DBR+1D grating	15.42 (+24%)			
DBR DBR+Grating		DBR+2D grating	16.32 (<mark>+31%</mark>)			
SiO ₂ n≈1.5			Triangular PhC	15.79 (+27%)		
 Improved PV cell efficiency is obtained for all wave optics structures. Careful design is needed. Cell production ? 			Woodpile PhC	15.42 (+24%)		
			Inverse opal PhC	15.73 (+26%)		
			* Recombination losses at metal surface are NOT taken into account * Data neglecting absorption losses are in parenthesis			

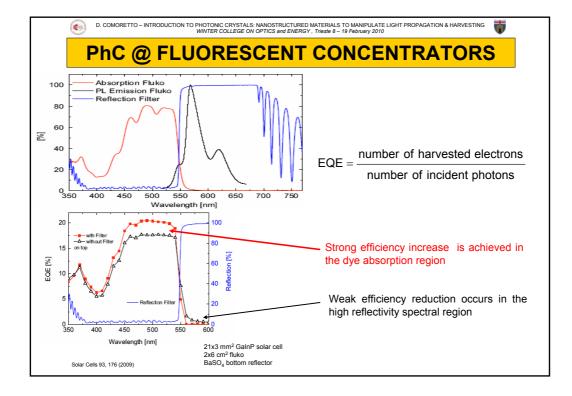


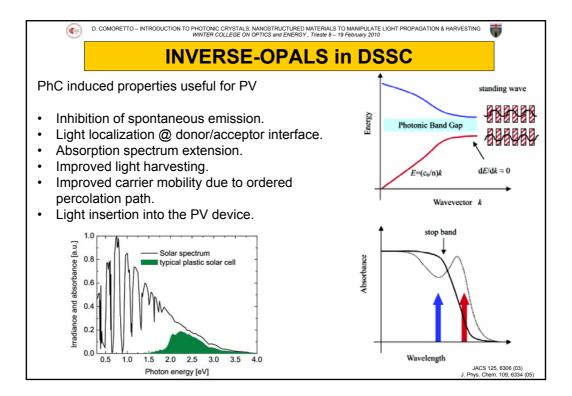


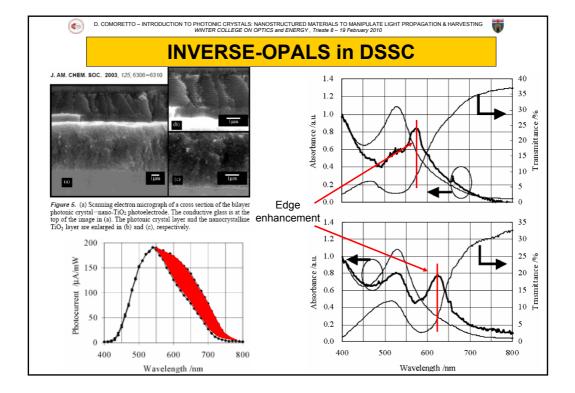


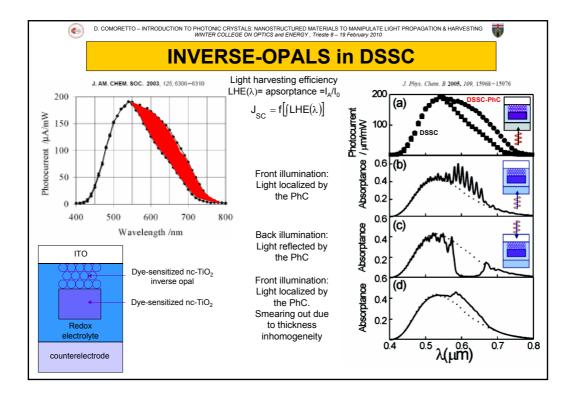


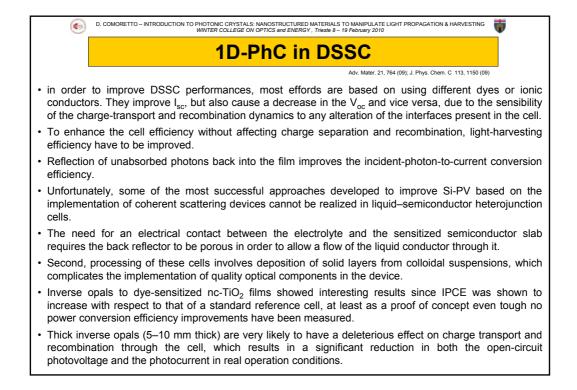


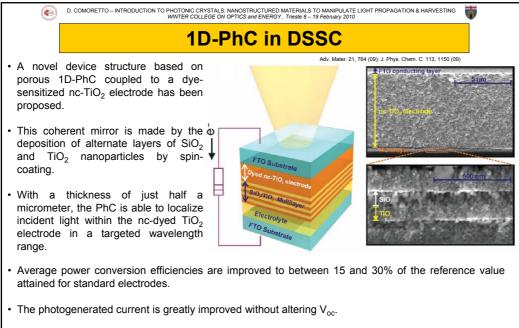












• The transparency of the cell, one of its added values, remains intact, contrary to what happens when scattering layers are employed to improve light harvesting.

